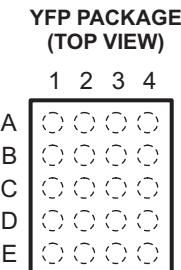


# MMC, SD CARD, Memory Stick™ VOLTAGE-TRANSLATION TRANSCEIVER AND LDO VOLTAGE REGULATOR WITH ESD PROTECTION AND EMI FILTERING

## FEATURES

- **Level Translator**
  - $V_{CCA}$  Range of 1.1 V to 3.6 V
  - Fast Propagation Delay (4 ns Max When Translating Between 1.8 V and 2.9 V)
- **Low-Dropout (LDO) Regulator**
  - 200-mA LDO Regulator With Enable
  - 2.9-V Output Voltage
  - 3.05-V to 5.5-V Input Voltage Range
  - Very Low Dropout: 200 mV at 200 mA
- **ESD Protection Exceeds JESD 22 (A Port)**
  - 2000-V Human-Body Model (A114-B)
  - 1000-V Charged-Device Model (C101)
- **$\pm 8$ -kV Contact Discharge IEC 61000-4-2 ESD (B Port)**



## TERMINAL ASSIGNMENTS

	1	2	3	4
<b>A</b>	DAT2A	$V_{CCA}$	WP/CD	DAT2B
<b>B</b>	DAT3A	$V_{BATT}$	$V_{CCB}$ O/P	DAT3B
<b>C</b>	CMDA	GND	GND	CMDB
<b>D</b>	DAT0A	CLKA	CLKB	DAT0B
<b>E</b>	DAT1A	CLK-f	EN	DAT1B

## DESCRIPTION/ORDERING INFORMATION

The TXS0206-29 is a complete solution for interfacing microprocessors with MultiMediaCards (MMCs), secure digital (SD) cards, and Memory Stick™ cards. It is comprised of a high-speed level translator, a low-dropout (LDO) voltage regulator, IEC level ESD protection, and EMI filtering circuitry.

The voltage-level translator has two supply voltage pins.  $V_{CCA}$  can be operated over the full range of 1.1 V to 3.6 V.  $V_{CCB}$  is set at 2.9 V and is supplied by an internal LDO. The integrated LDO accepts input voltages from 3.05V to as high as 5.5 V and outputs 2.9 V, 200 mA to the B-side circuitry and to the external memory card. The TXS0206-29 enables system designers to easily interface low-voltage microprocessors to memory cards operating at 2.9 V.

Memory card standards recommend high-ESD protection for devices that connect directly to the external memory card. To meet this need, the TXS0206-29 incorporates  $\pm 8$ -kV Contact Discharge protection on the card side.

Since memory cards are widely used in mobile phones, PDAs, digital cameras, personal media players, camcorders, set-top boxes, etc. Low static power consumption and small package size make the TXS0206-29 an ideal choice for these applications. The TXS0206-29 is offered in a 20-bump wafer chip scale package (WCSP). This package has dimensions of 1.96 mm x 1.56 mm, with a 0.4-mm ball pitch for effective board-space savings

## ORDERING INFORMATION<sup>(1)</sup>

T <sub>A</sub>	PACKAGE <sup>(2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(3)</sup>
-40°C to 85°C	WCSP – YFP (Pb-free)	Tape and reel	TXS0206-29YFPR _ _ _ 3 V 2

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at [www.ti.com](http://www.ti.com).

(2) Package drawings, thermal data, and symbolization are available at [www.ti.com/packaging](http://www.ti.com/packaging).

(3) The actual top-side marking has three preceding characters to denote year, month, and sequence code.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

## REFERENCE DESIGN

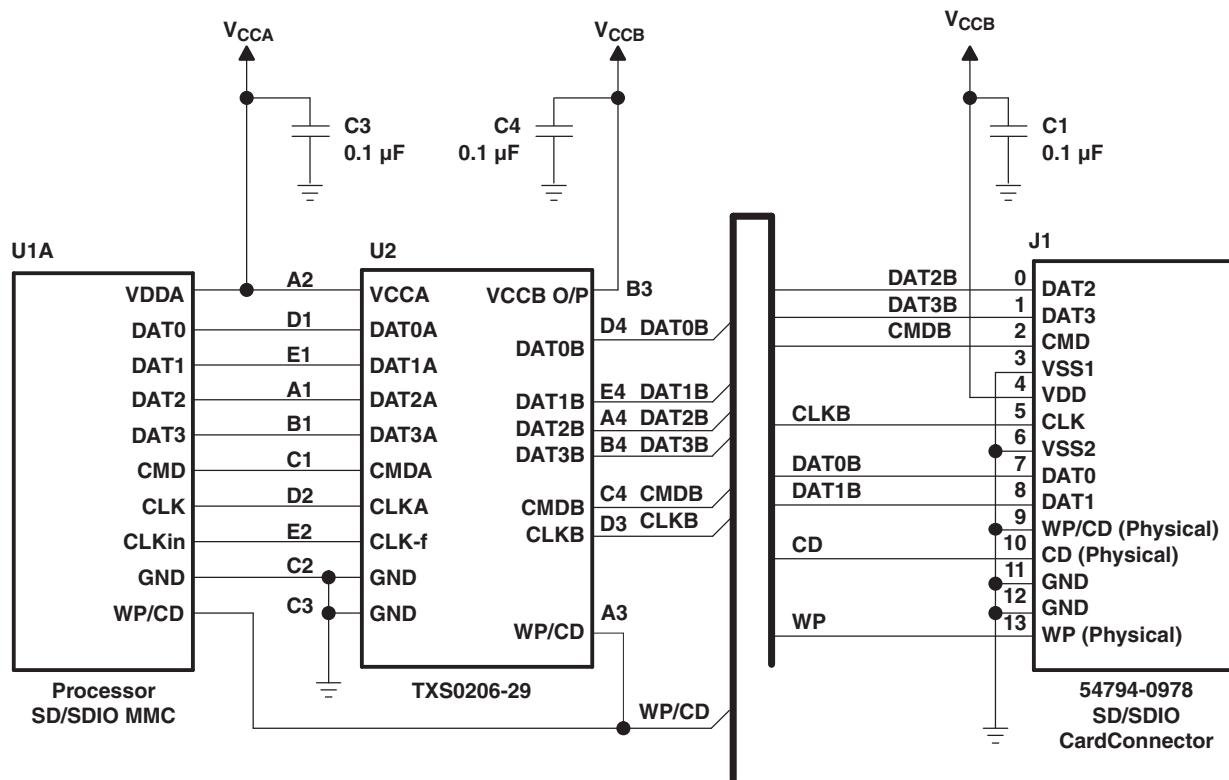


Figure 1. Interfacing With SD/SDIO Card

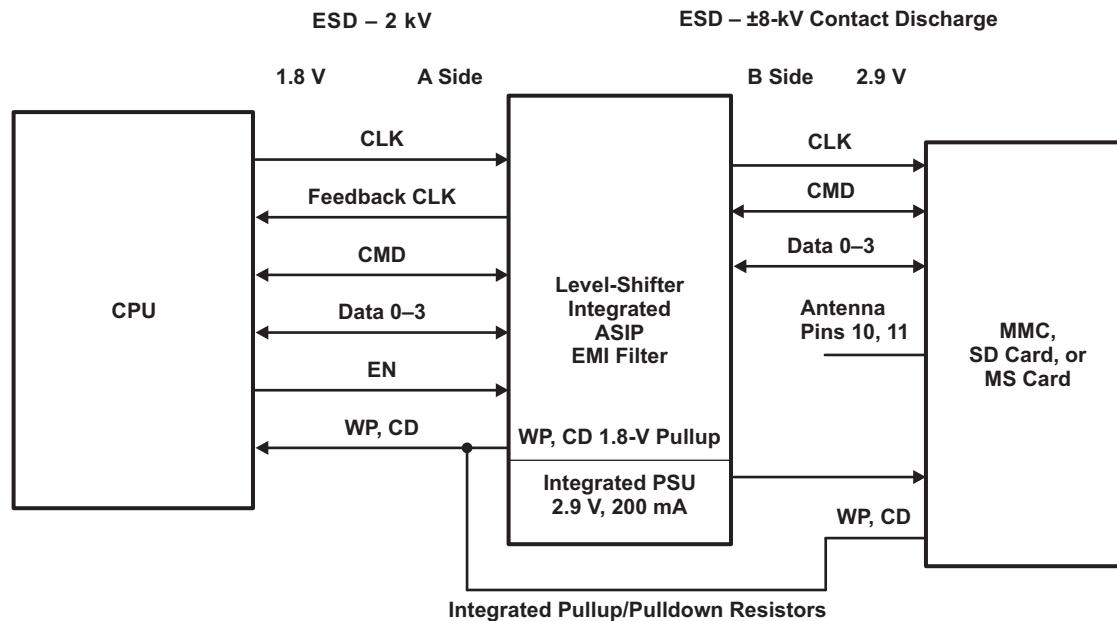


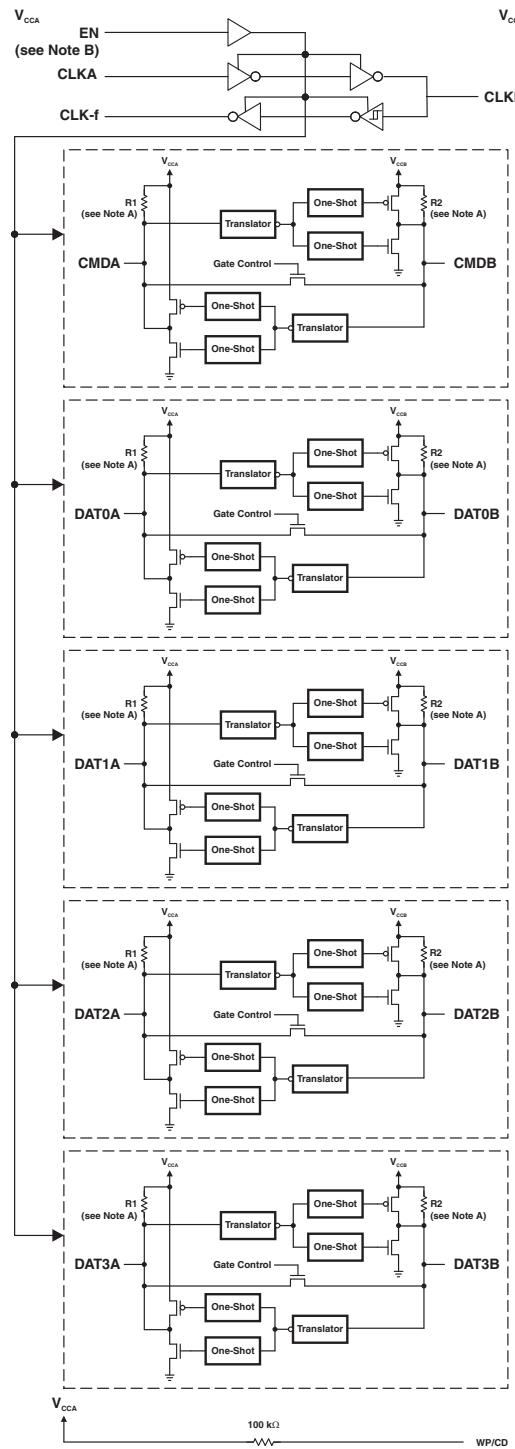
Figure 2. Typical Application Circuit

**Table 1. LOGIC TABLE**

EN	LDO	TRANSLATOR I/Os
L	Disabled	Disabled, pulled to $V_{CCA}$ , $V_{CCB}$ O/P through $R_1$ and $R_2$ at 70k $\Omega$ pullup resistors respectively
H	Active	Active

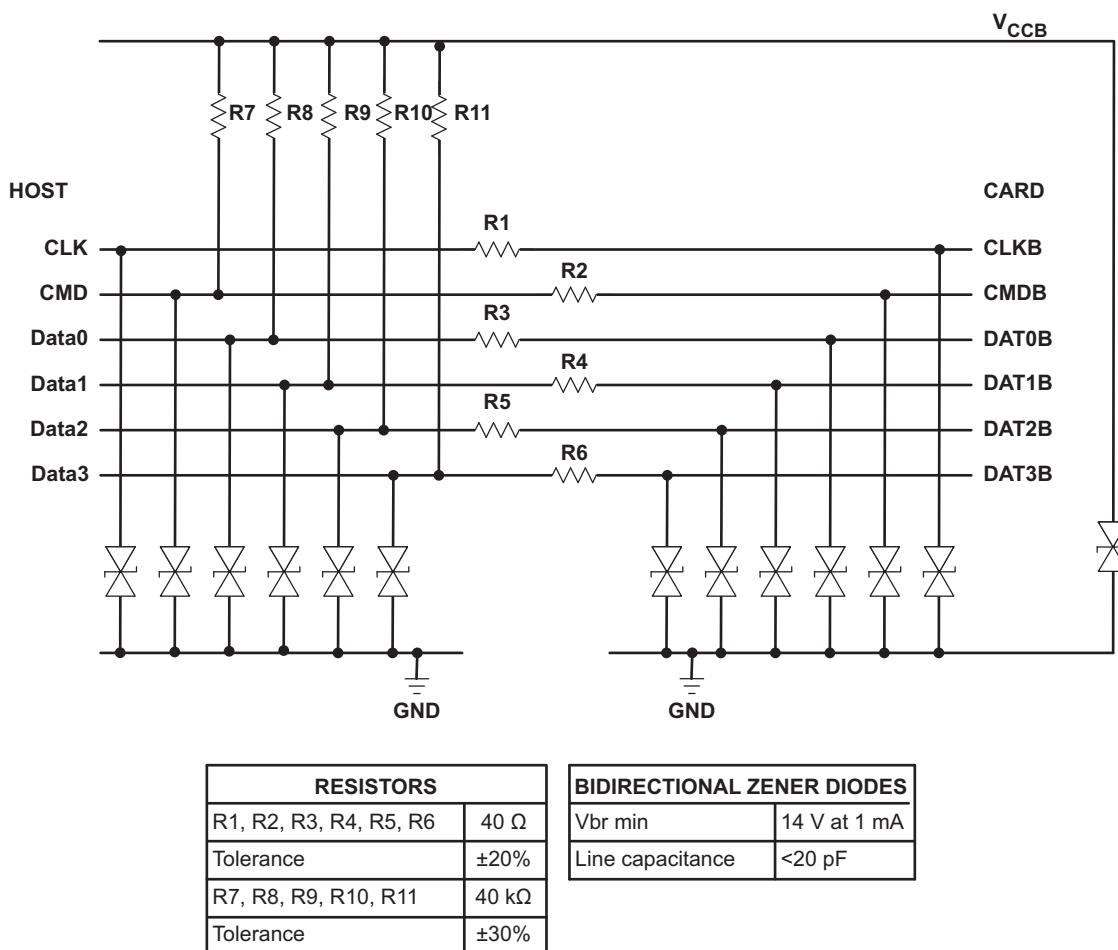
**TERMINAL FUNCTIONS**

TERMINAL		TYPE	DESCRIPTION
NO.	NAME		
A1	DAT2A	I/O	Data bit 2 connected to host. Referenced to $V_{CCA}$ . Includes $R_1$ pullup resistor to $V_{CCA}$ (see Note A).
A2	$V_{CCA}$	Power	A-port supply voltage. $V_{CCA}$ powers all A-port I/Os and control inputs.
A3	WP/CD	Output	Connected to write protect on the mechanical connector. The WP pin has an internal 100-k $\Omega$ pullup resistor to $V_{CCA}$ .
A4	DAT2B	I/O	Data bit 2 connected to memory card. Referenced to $V_{CCB}$ O/P. Includes $R_2$ pullup resistor to $V_{CCB}$ O/P (see Note A).
B1	DAT3A	I/O	Data bit 3 connected to host. Referenced to $V_{CCA}$ . Includes $R_1$ pullup resistor to $V_{CCA}$ (see Note A).
B2	$V_{BATT}$	Input	LDO input voltage from Battery-Supply
B3	$V_{CCB}$ O/P	Output	LDO output voltage and B-port supply voltage. $V_{CCB}$ O/P powers all B-port I/Os.
B4	DAT3B	I/O	Data bit 3 connected to memory card. Referenced to $V_{CCB}$ O/P. Includes $R_2$ pullup resistor to $V_{CCB}$ O/P (see Note A).
C1	CMDA	I/O	Command bit connected to host. Referenced to $V_{CCA}$ . Includes $R_1$ pullup resistor to $V_{CCA}$ (see Note A).
C2, C3	GND		Ground
C4	CMDB	I/O	Command bit connected to memory card. Referenced to $V_{CCB}$ O/P. Includes $R_2$ pullup resistor to $V_{CCB}$ O/P (see Note A).
D1	DAT0A	I/O	Data bit 0 connected to host. Referenced to $V_{CCA}$ . Includes $R_1$ pullup resistor to $V_{CCA}$ (see Note A).
D2	CLKA	Input	Clock signal connected to host. Referenced to $V_{CCA}$ .
D3	CLKB	Output	Clock signal connected to memory card. Referenced to $V_{CCB}$ O/P.
D4	DAT0B	I/O	Data bit 0 connected to memory card. Referenced to $V_{CCB}$ O/P. Includes $R_2$ pullup resistor to $V_{CCB}$ O/P (see Note A).
E1	DAT1A	I/O	Data bit 1 connected to host. Referenced to $V_{CCA}$ . Includes $R_1$ pullup resistor to $V_{CCA}$ (see Note A).
E2	CLK-f	Output	Clock feedback to host for resynchronizing data to a processor. Leave unconnected if not used.
E3	EN	Input	Enable/disable control. Pull EN low to place all outputs in Hi-Z state and to disable the LDO. Referenced to $V_{CCA}$ .
E4	DAT1B	I/O	Data bit 1 connected to memory card. Referenced to $V_{CCB}$ O/P. Includes $R_2$ pullup resistor to $V_{CCB}$ O/P (see Note A).

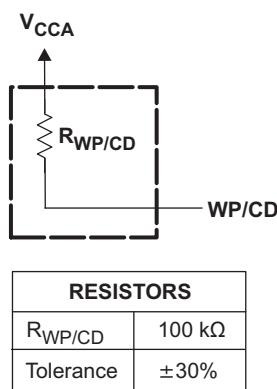


- A.  $R_1$  and  $R_2$  resistor values are determined based upon the logic level applied to the A port or B port as follows:
  - $R_1$  and  $R_2 = 40\text{ k}\Omega$  when a logic level low is applied to the A port or B port.
  - $R_1$  and  $R_2 = 4\text{ k}\Omega$  when a logic level high is applied to the A port or B port.
  - $R_1$  and  $R_2 = 70\text{ k}\Omega$  when the port is deselected (or in High-Z or 3-state).
- B. EN controls all output buffers. When EN = low, all outputs are Hi-Z.

**Figure 3. Logic Diagram**



**Figure 4. ASIP Block Diagram**



**Figure 5. WP/CD Pullup Resistor**

**ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>****Level Translator**

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{CCA}$	Supply voltage range	-0.5	4.6	V
$V_I$	Input voltage range	I/O ports (A port)	-0.5	4.6
		I/O ports (B port)	-0.5	4.6
		Control inputs	-0.5	4.6
$V_O$	Voltage range applied to any output in the high-impedance or power-off state	A port	-0.5	4.6
		B port	-0.5	4.6
$V_O$	Voltage range applied to any output in the high or low state	A port	-0.5	4.6
		B port	-0.5	4.6
$I_{IK}$	Input clamp current	$V_I < 0$	-50	mA
$I_{OK}$	Output clamp current	$V_O < 0$	-50	mA
$I_O$	Continuous output current		$\pm 50$	mA
	Continuous current through $V_{CCA}$ or GND		$\pm 100$	mA
$T_{stg}$	Storage temperature range	-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

**THERMAL IMPEDANCE RATINGS**

	TYP	UNIT	
$\theta_{JA}$	Package thermal impedance <sup>(1)</sup>	117	°C/W

(1) The package thermal impedance is calculated in accordance with JESD 51-7.

**ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>****LDO**

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT	
$V_{IN}$	Input voltage range	2.3	6.5	V
$V_{OUT}$	Output voltage range	-0.3	4.6	V
	Peak output current		220	mA
	Continuous total power dissipation		TBD	mW
$T_J$	Junction temperature range	-55	150	°C
$T_{stg}$	Storage temperature range	-55	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

**RECOMMENDED OPERATING CONDITIONS<sup>(1)</sup>**
**Level Translator**

		$V_{CCA}$	$V_{CCB}$	MIN	MAX	UNIT
$V_{CCA}$	Supply voltage			1.1	3.6	V
$V_{IH}$	High-level input voltage	A-Port CMD and DATA I/Os	1.1 V to 1.95 V	2.9 V	$V_{CCI} - 0.2$	$V_{CCI}$
			1.95 V to 3.6 V		$V_{CCI} - 0.4$	$V_{CCI}$
		B-Port and DATA I/Os	1.1 V to 1.95 V	2.9 V	$V_{CCI} - 0.2$	$V_{CCI}$
			1.95 V to 3.6 V		$V_{CCI} - 0.4$	$V_{CCI}$
		OE and CLKA	1.1 V to 3.6 V		$V_{CCI} \times 0.65$	$V_{CCI}$
		A-Port CMD and DATA I/Os	1.1 V to 1.95 V	2.9 V	0	0.15
$V_{IL}$	Low-level input voltage		1.95 V to 3.6 V		0	0.15
	B-Port CMD and DATA I/Os	1.1 V to 1.95 V	2.9 V	0	0.15	
		1.95 V to 3.6 V		0	0.15	
	OE and CLKA	1.1 V to 3.6 V		0	$V_{CCI} \times 0.35$	
	Active state			0	$V_{CCO}$	
		3-state			V	
$I_{OH}$	High-level output current (CLK-f output)	1.1 V to 1.3 V	2.9 V			-0.5
		1.4 V to 1.6 V				-1
		1.65 V to 1.95 V				-2
		2.3 V to 2.7 V				-4
		3 V to 3.6 V				-8
		1.1 V to 1.3 V				0.5
$I_{OL}$	Low-level output current (CLK-f output)	1.4 V to 1.6 V	2.9 V			1
		1.65 V to 1.95 V				2
		2.3 V to 2.7 V				4
		3 V to 3.6 V				8
$I_{OH}$	High-level output current (CLK output)		2.9 V			-8 mA
$I_{OL}$	Low-level output current (CLK output)		2.9 V			8 mA
$\Delta t/\Delta v$	Input transition rise or fall rate					5 ns/V
$T_A$	Operating free-air temperature			-40	85	°C

(1) All unused data inputs of the device must be held at  $V_{CCI}$  or GND to ensure proper device operation. See the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#).

**RECOMMENDED OPERATING CONDITIONS  
LDO**

		MIN	MAX	UNIT
$I_{OUT(PK)}$	Peak output current	200		mA
$C_{OUT}$	Output capacitance	1	100	μF
$T_J$	Operating junction temperature	-40	125	°C

## ELECTRICAL CHARACTERISTICS

### Level Translator

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CCA</sub>	V <sub>CCB</sub> O/P	MIN	TYP <sup>(1)</sup>	MAX	UNIT			
V <sub>OH</sub>	A port (CLK-f output)	I <sub>OH</sub> = -100 $\mu$ A	1.1 V to 3.6 V	2.9 V	V <sub>CCA</sub> $\times$ 0.8	0.8	V			
		I <sub>OH</sub> = -0.5 mA	1.1 V		0.8					
		I <sub>OH</sub> = -1 mA	1.4 V		1.05					
		I <sub>OH</sub> = -2 mA	1.65 V		1.2					
		I <sub>OH</sub> = -4 mA	2.3 V		1.75					
		I <sub>OH</sub> = -8 mA	3 V		2.3					
	A port (DAT and CMD outputs)	I <sub>OH</sub> = -20 $\mu$ A	1.1 V to 3.6 V		V <sub>CCA</sub> $\times$ 0.8					
V <sub>OL</sub>	A port (CLK-f output)	I <sub>OL</sub> = 100 $\mu$ A	1.1 V to 3.6 V	2.9 V	V <sub>CCA</sub> $\times$ 0.8	0.35	V			
		I <sub>OL</sub> = 0.5 mA	1.1 V		0.35					
		I <sub>OL</sub> = 1 mA	1.4 V		0.35					
		I <sub>OL</sub> = 2 mA	1.65 V		0.45					
		I <sub>OL</sub> = 4 mA	2.3 V		0.55					
		I <sub>OL</sub> = 8 mA	3 V		0.7					
	A port (DAT and CMD outputs)	I <sub>OL</sub> = 135 $\mu$ A	1.1 V to 3.6 V	2.9 V	0.4	0.4	V			
		I <sub>OL</sub> = 180 $\mu$ A			0.4					
		I <sub>OL</sub> = 220 $\mu$ A			0.4					
		I <sub>OL</sub> = 300 $\mu$ A			0.4					
		I <sub>OL</sub> = 400 $\mu$ A			0.55					
V <sub>OH</sub>	B port (CLK output)	I <sub>OH</sub> = -100 $\mu$ A	1.1 V to 3.6 V	2.9 V	V <sub>CCB</sub> O/P $\times$ 0.8	2.3	V			
		I <sub>OH</sub> = -8 mA			0.8					
	B port (DAT output)	I <sub>OH</sub> = -20 $\mu$ A	1.1 V to 3.6 V	2.9 V	V <sub>CCB</sub> O/P $\times$ 0.8	0.8				
					0.7					
V <sub>OL</sub>	CLKB output port	I <sub>OL</sub> = 100 $\mu$ A	1.1 V to 3.6 V	2.9 V	V <sub>CCB</sub> O/P $\times$ 0.8	0.4	V			
		I <sub>OL</sub> = 8 mA			0.7					
	B port (DAT and CMD outputs)	I <sub>OL</sub> = 135 $\mu$ A	1.1 V to 3.6 V	2.9 V	0.4	0.4	V			
		I <sub>OL</sub> = 180 $\mu$ A			0.4					
		I <sub>OL</sub> = 220 $\mu$ A			0.4					
		I <sub>OL</sub> = 300 $\mu$ A			0.4					
		I <sub>OL</sub> = 400 $\mu$ A			0.55					
I <sub>I</sub>	Control inputs	V <sub>I</sub> = V <sub>CCA</sub> or GND	1.1 V to 3.6 V	2.9 V		$\pm 1$	$\mu$ A			
I <sub>CCA</sub>		V <sub>I</sub> = V <sub>CCI</sub> or GND, I <sub>O</sub> = 0	1.1 V to 3.6 V	2.9 V		6	$\mu$ A			
I <sub>CCB</sub>		V <sub>I</sub> = V <sub>CCI</sub> or GND, I <sub>O</sub> = 0	1.1 V to 3.6 V	2.9 V		5	$\mu$ A			
C <sub>io</sub>	A port				5.5	6.5	pF			
	B port				15	17.5				
C <sub>i</sub>	Control inputs	V <sub>I</sub> = V <sub>CCA</sub> or GND			3.5	4.5	pF			
	Clock input				3	4				

(1) All typical values are at T<sub>A</sub> = 25°C.

## ELECTRICAL CHARACTERISTICS LDO

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP <sup>(1)</sup>	MAX	UNIT		
$V_{BATT}$	Input voltage			$V_{OUT} + V_{DO}$		5.5	V		
$V_{OUT}$	Output voltage	Nominal $T_A = 25^\circ\text{C}$		2.9		3.05	V		
		All conditions		2.75					
$\Delta V_{OUT}$	Output voltage tolerance	Nominal $T_A = 25^\circ\text{C}$		$\pm 3$		%			
$V_{DO}$	Dropout voltage	$I_{OUT} = 200 \text{ mA}$		200		250	mV		
$I_{GND}$	Ground-pin current	$I_{OUT} = 0$		40		400	$\mu\text{A}$		
		$I_{OUT} < 100 \text{ mA}$		200					
		$100 \text{ mA} \leq I_{OUT} \leq 200 \text{ mA}$		400					
$I_{OUT(\text{SC})}$	Short-circuit current	$R_L = 0 \Omega$		300		mA			
PSRR	Power-supply rejection ratio	$V_{IN} = 3.05 \text{ V}$ , $V_{OUT} = 2.9 \text{ V}$ , $C_{NR} = 0.01 \mu\text{F}$ , $I_{OUT} = 200 \text{ mA}$		$f = 1 \text{ kHz}$	50		dB		
				$f = 10 \text{ kHz}$	40				
$t_{\text{STR}}$	Start-up time	$V_{OUT} = 2.9 \text{ V}$ , $I_{OUT} = 200 \text{ mA}$ , $C_{OUT} = 2.2 \mu\text{F}$		200		$\mu\text{s}$			

(1) All typical values are at  $T_A = 25^\circ\text{C}$ .

## TIMING REQUIREMENTS

over recommended operating free-air temperature range,  $V_{CCB} = 2.9 \text{ V} \pm 5\%$  (unless otherwise noted)

			$V_{CCA} = 1.2 \text{ V} \pm 0.1 \text{ V}$		$V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$		$V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$		$V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$		$V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate	Command	Push-pull driving	40	60	60	60	60	60	60	60	Mbps		
		Open-drain driving	1	1	1	1	1	1	1	1			
	Clock	Push-pull driving	60	60	60	60	60	60	60	60	MHz		
	Data		40	60	60	60	60	60	60	60			
$t_w$	Pulse duration	Command	25	17	17	17	17	17	17	17	ns		
		Open-drain driving	1	1	1	1	1	1	1	1			
	Clock	Push-pull driving	8.3	8.3	8.3	8.3	8.3	8.3	8.3	8.3	ns		
	Data		25	17	17	17	17	17	17	17			

## SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $V_{CCB} = 2.9 \text{ V} \pm 5\%$  (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	$V_{CCA} = 1.2 \text{ V} \pm 0.1 \text{ V}$		$V_{CCA} = 1.5 \text{ V} \pm 0.1 \text{ V}$		$V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$		$V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$		$V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
$t_{pd}$	CMDA	CMDB	Push-pull driving	10.8		6.1		4.6		3.7		3.8		ns
			Open-drain driving (H-to-L)	3.2	10.6	2.7	6.6	2.4	5.5	2.1	4.4	2	4.1	
			Open-drain driving (L-to-H)	71	175	83	180	89	201	98	249	101	233	
	CMDB	CMDA	Push-pull driving	12		6.8		5.2		4.1		3.4		
			Open-drain driving (H-to-L)	2.9	9.4	2.1	7.3	2	6.4	2	5.7	2.2	4.6	
			Open-drain driving (L-to-H)	77	243	87	214	93	215	99	261	105	248	
	CLKA	CLKB	Push-pull driving	11.7		6.2		4.7		3.7		3.5		
	DATxA	DATxB	Push-pull driving	11.1		6.2		4.7		3.7		3.7		
	DATxB	DATxA		11.5		6.2		5		3.9		6.2		
	CLKA	CLK-f	Push-pull driving	24.7		13		8.9		6.8		4.8		
$t_{en}$	EN	B-port	Push-pull driving	1		1		1		1		1		$\mu\text{s}$
	EN	A-port	Push-pull driving	1		1		1		1		1		
$t_{dis}$	EN	B-port	Push-pull driving	40		39		35		38		34		ns
	EN	A-port	Push-pull driving	40		38		38		38		36		
$t_{rA}$	CMDA rise time	Push-pull driving	1.6	12.2	0.4	8.3	1.1	5.9	1.9	3.3	0.8	4.2		ns
		Open-drain driving	32	120	44	127	52	150	62	201	74	194		
	CLK-f rise time	Push-pull driving	0.6	12.7	0.5	7.2	0.4	4.5	0.7	1.5	0.7	1.4		
			1.6	11.6	0.6	8.4	1	6.3	1.8	4.2	1.1	3.3		
$t_{rB}$	CMDB rise time	Push-pull driving	1.7	6.7	0.5	5.6	1	5.2	1.5	5.2	1.9	5		ns
		Open-drain driving	66	214	71	196	73	184	76	214	79	185		
	CLKB rise time	Push-pull driving	1.7	4.8	1.5	4.9	1.5	4.9	1.6	5	1.6	5.1		
			0.4	6.8	0.6	5	0.2	5.2	0.9	5.3	1	14		
$t_{fA}$	CMDA fall time	Push-pull driving	0.8	4	0.8	2.3	0.2	3.1	0.3	1.5	1	2.3		ns
		Open-drain driving	1.6	3.9	1.6	3.7	1.6	3.7	1.6	3.7	1.6	3.9		
	CLK-f fall time	Push-pull driving	1	4	0.4	6.8	0.1	1.5	0.3	2.8	0.6	1.3		
			1	3.9	0.1	3.8	0.2	2.7	0.3	2.9	0.4	1.8		
$t_{fB}$	CMDB fall time	Push-pull driving	1.5	4.5	1.4	5.4	1.6	5	1.6	5.6	0.8	6.3		ns
		Open-drain driving	1	4.3	1	2.3	0.8	1.9	0.8	1.6	0.9	1.3		
	CLKB fall time	Push-pull driving	1.6	4	1.6	4.1	1.7	4.2	1.7	4.5	0.9	5.1		
			1	4.8	2.3	4.3	0.8	4.9	0.2	4.9	0.8	6.9		
$t_{sk(O)}$	Channel-to-channel skew	Push-pull driving	1		1		1		1		1		ns	
Max data rate	Command	Push-pull driving	40		60		60		60		60		Mbps	
		Open-drain driving	1		1		1		1		1			
	Clock	Push-pull driving	60		60		60		60		60		MHz	
	Data		40		60		60		60		60		Mbps	

## OPERATING CHARACTERISTICS

$T_A = 25^\circ\text{C}$ ,  $V_{CCB} = 2.9\text{ V}$

PARAMETER		TEST CONDITIONS	$V_{CCA}$ TYP						UNIT	
			1.2 V	1.5 V	1.8 V	2.5 V	3 V	3.3 V		
$C_{pdA}$ <sup>(1)</sup>	A-port input, B-port output	CLK Enabled	$C_L = 0$ , $f = 10\text{ MHz}$ , $t_r = t_f = 1\text{ ns}$	15	15	15	15.7	17.1	17.1	
				6.3	6.4	6.5	6.5	6.5	6.5	
	B-port input, A-port output	DATA Enabled		12.5	12.3	12.3	12.5	14	14	
				0.2	0.2	0.2	0.3	0.3	0.3	
	A-port input, B-port output	CLK Disabled		1.2	1.2	1.2	1.2	1.2	1.2	
				0.2	0.2	0.2	0.3	0.3	0.3	
$C_{pdB}$ <sup>(1)</sup>	A-port input, B-port output	DATA Enabled		31.2	30.6	30.3	29.5	28.5	28.5	
				28.1	27.2	27	26.9	27	27	
	B-port input, A-port output	CLK Enabled		12.9	12.8	12.9	13.2	13.2	13.2	
				0.6	0.5	0.5	0.5	0.5	0.6	
	A-port input, B-port output	DATA Disabled		0.6	0.5	0.5	0.5	0.5	0.6	
				1.2	1.2	1.2	1	1	1	

(1) Power dissipation capacitance per transceiver

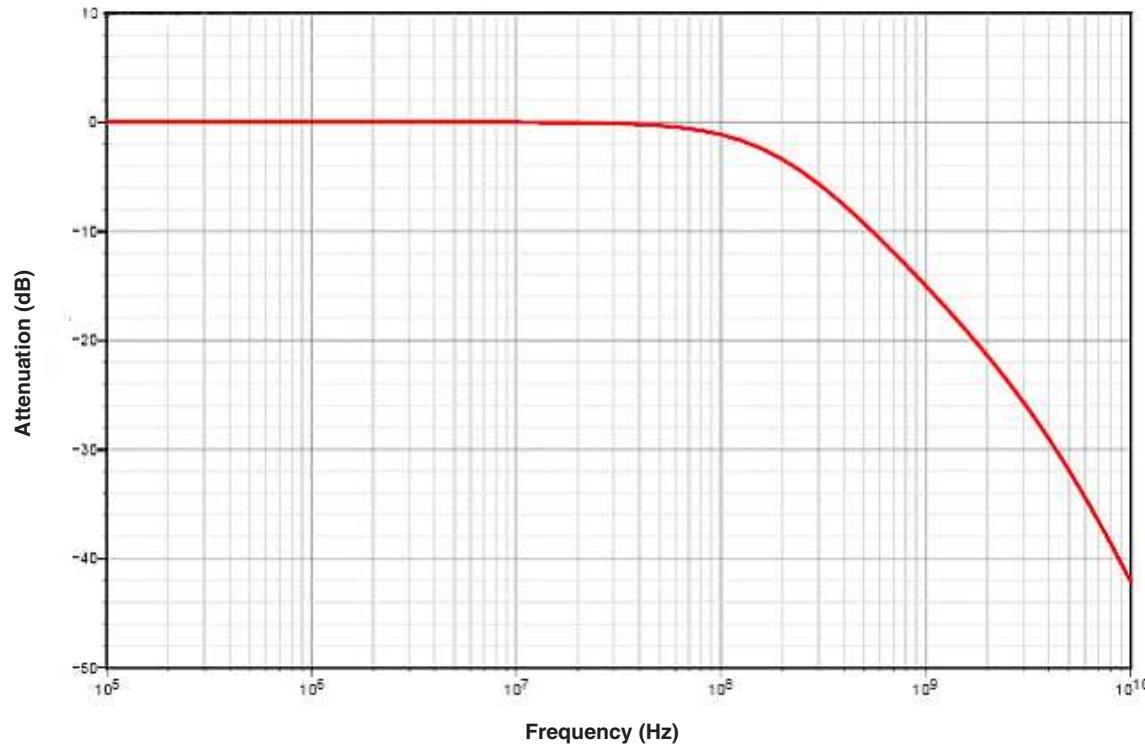


Figure 6. Typical ASIP EMI Filter Frequency Response

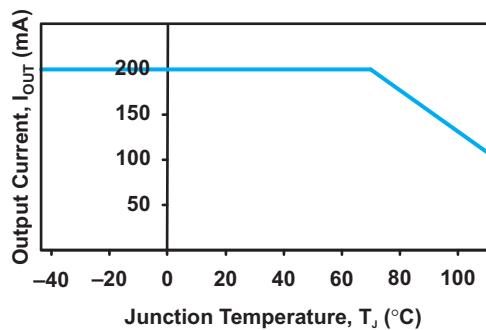
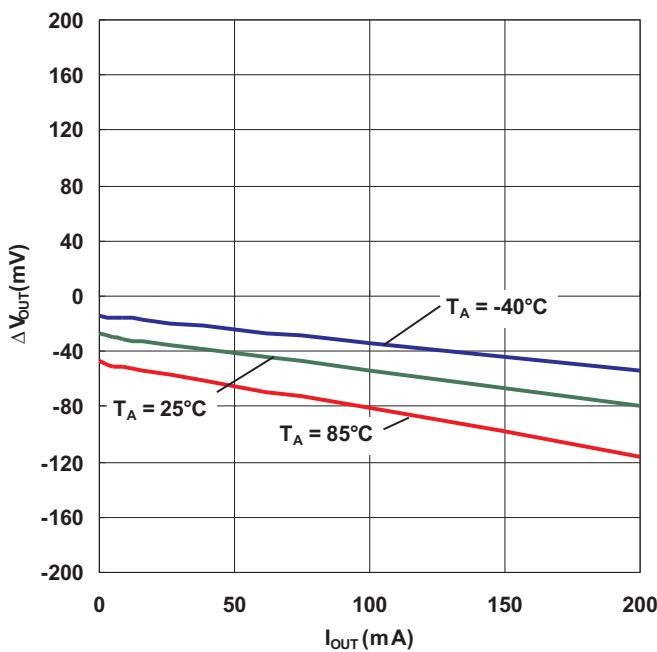


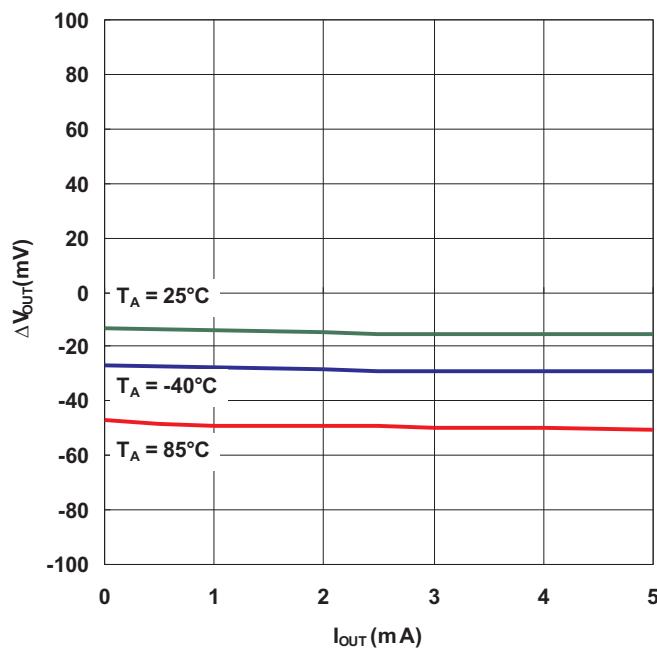
Figure 7. LDO Output Current Derating

### TYPICAL CHARACTERISTICS

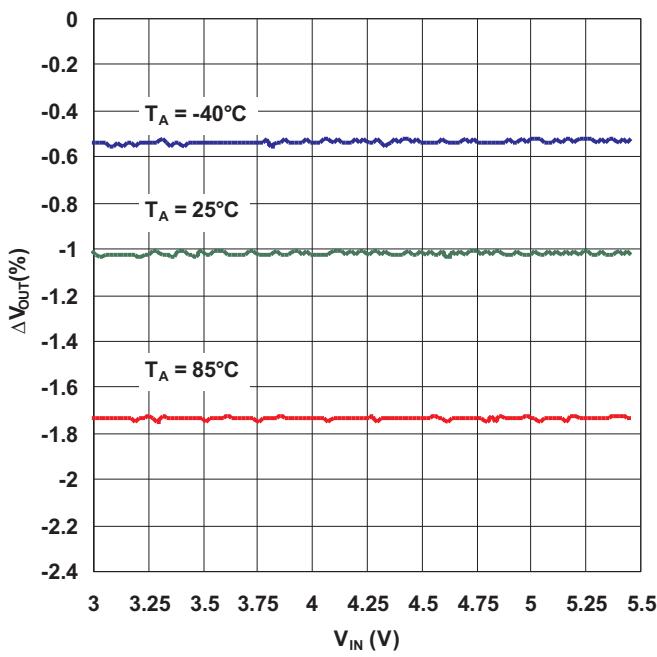
#### LOAD REGULATION



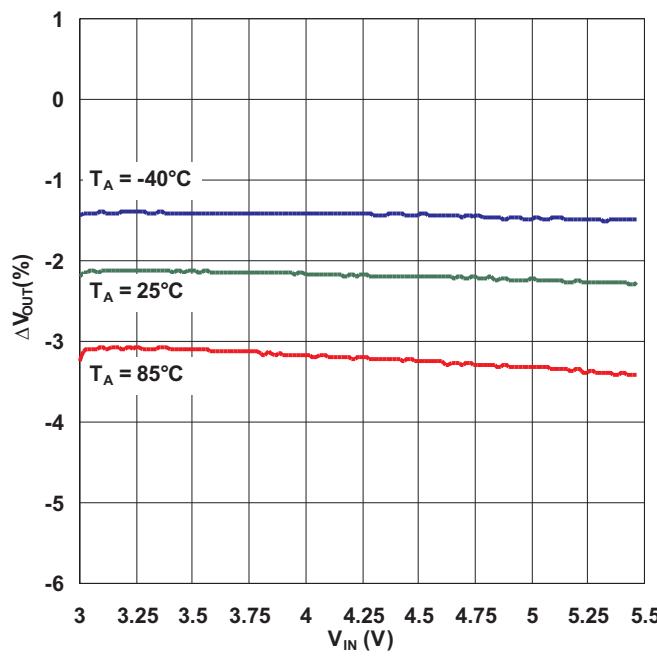
#### LOAD REGULATION, LIGHT LOADS



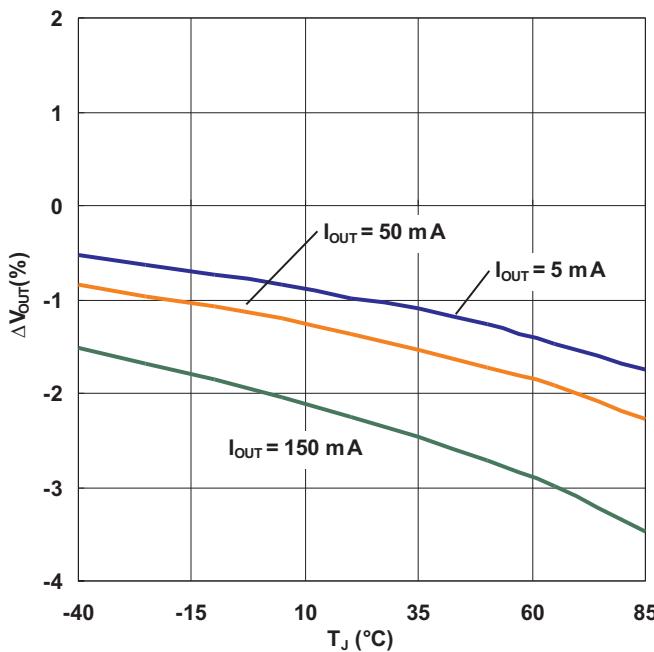
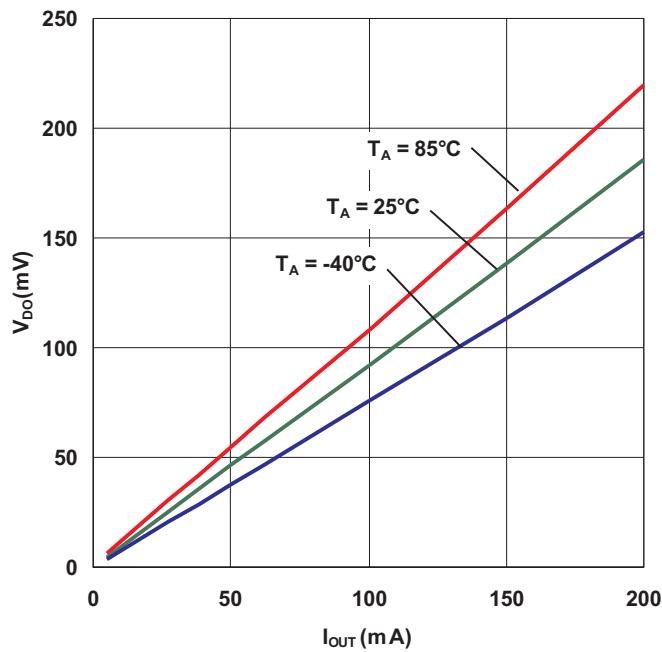
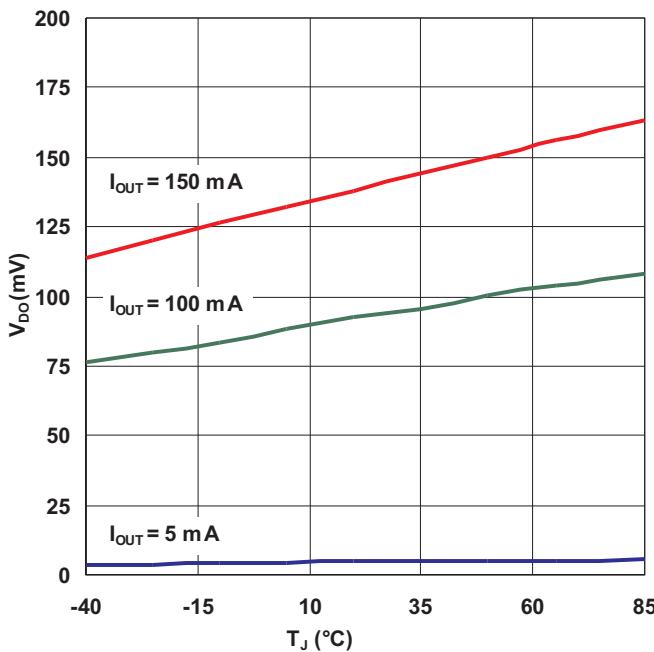
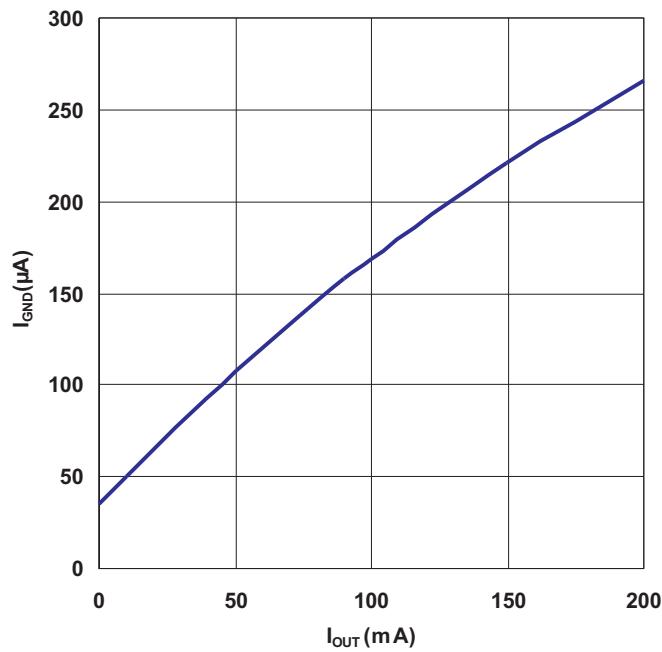
#### LINE REGULATION ( $I_{out} = 5\text{ mA}$ )

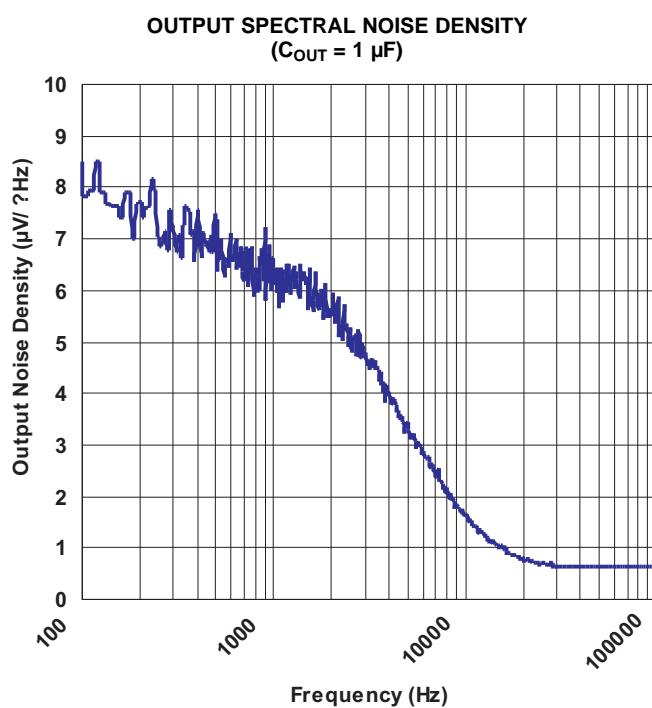
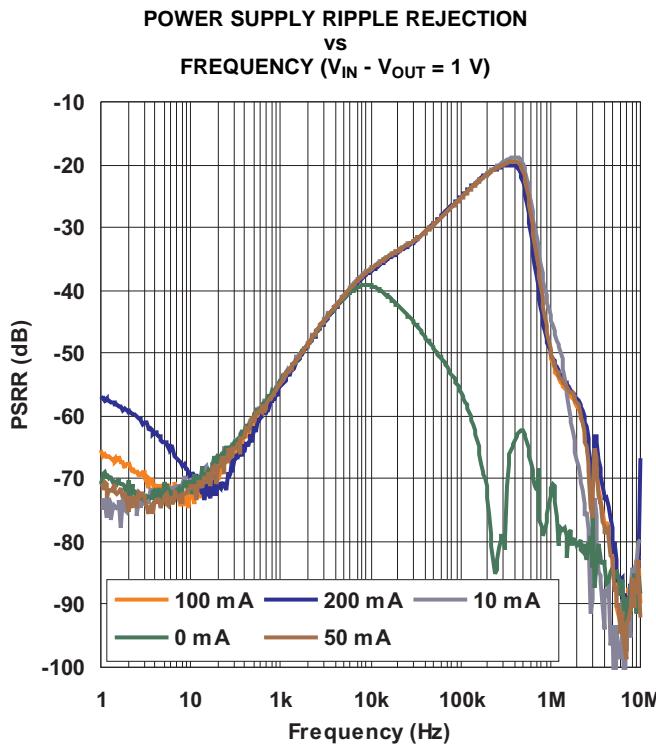
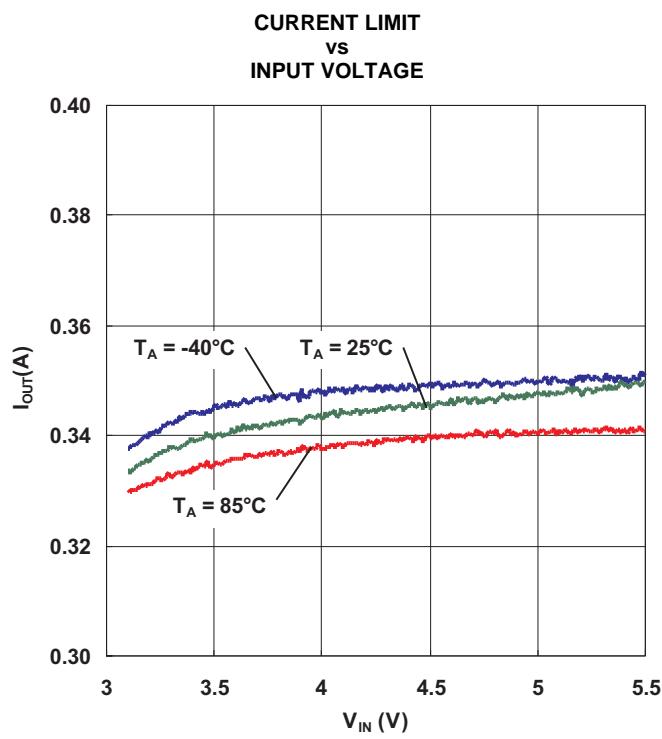
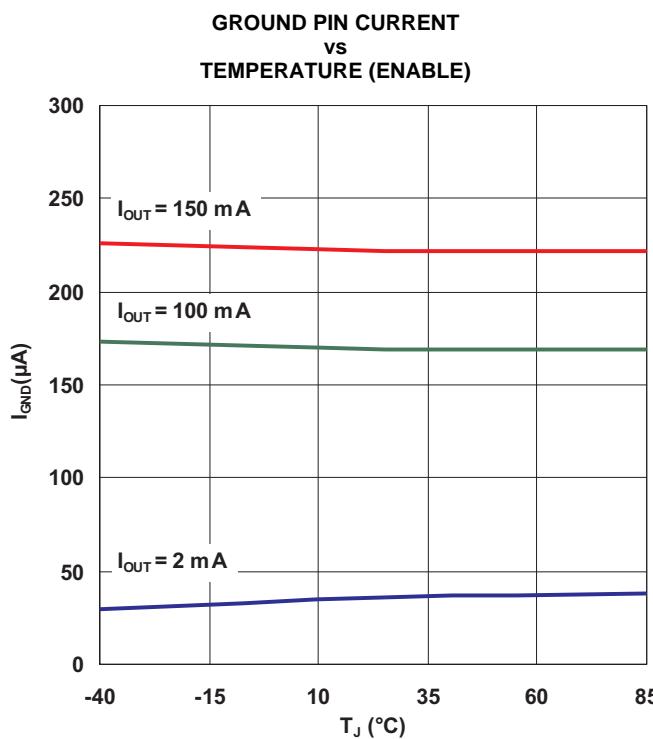


#### LINE REGULATION ( $I_{out} = 150\text{ mA}$ )

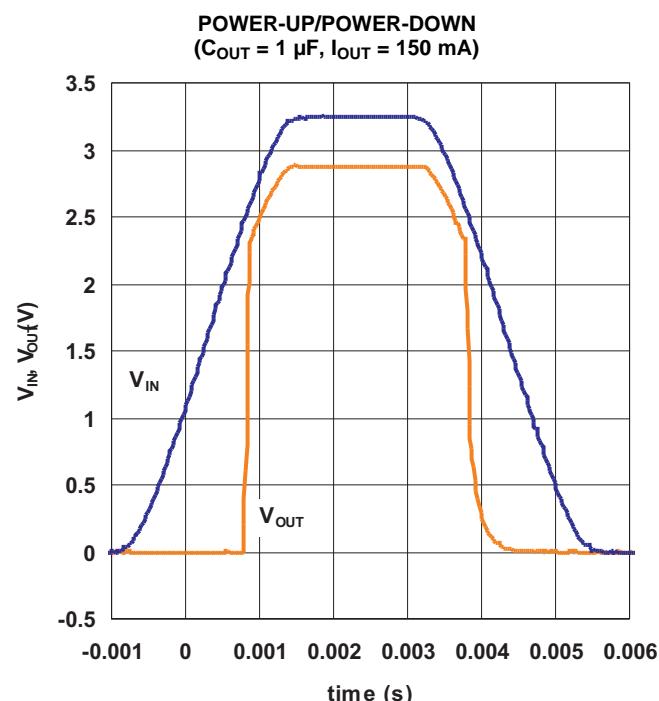
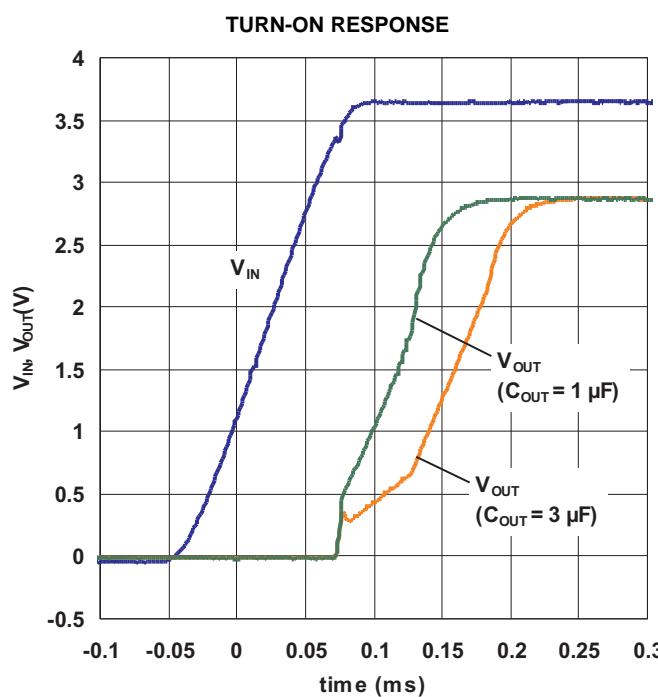
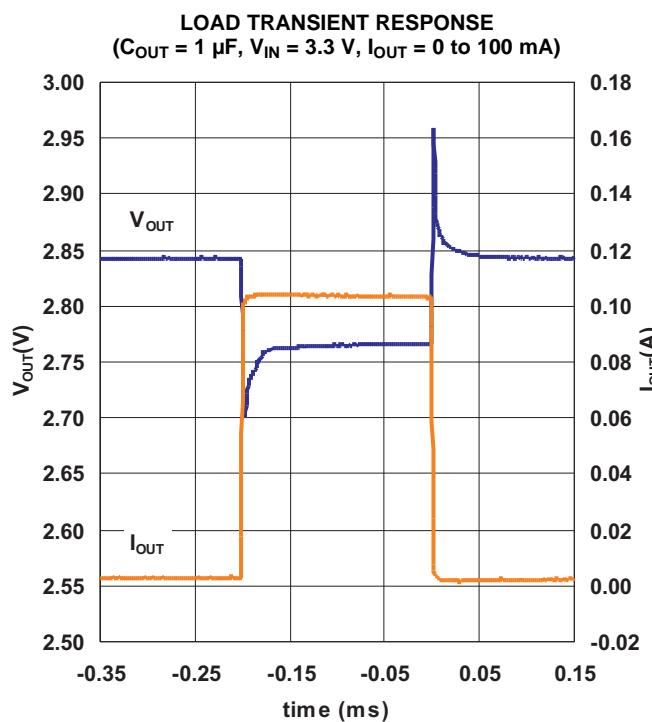
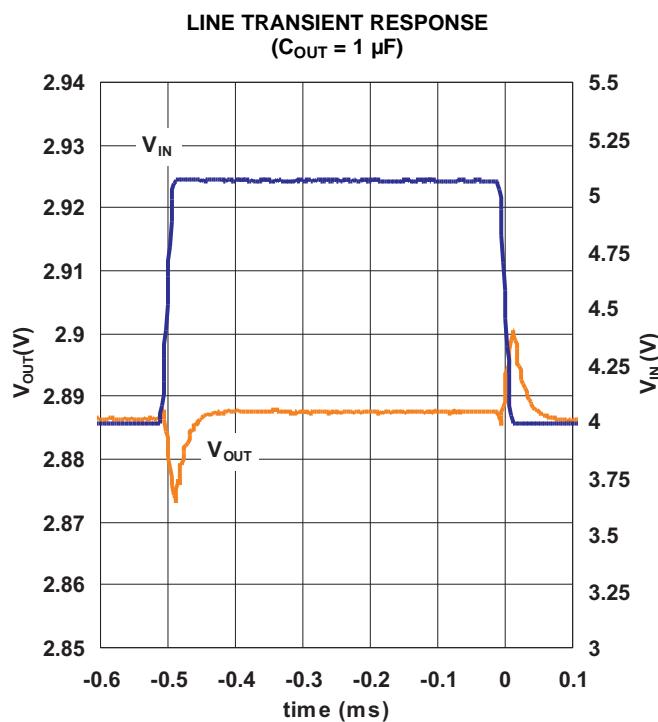


## TYPICAL CHARACTERISTICS (continued)

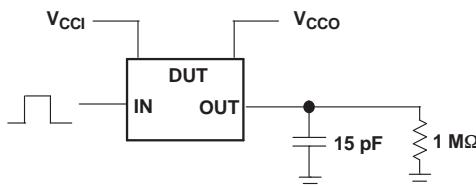
OUTPUT VOLTAGE  
vs  
TEMPERATUREDROPOUT VOLTAGE  
vs  
OUTPUT CURRENTDROPOUT VOLTAGE  
vs  
TEMPERATUREGROUND PIN CURRENT  
vs  
OUTPUT CURRENT

**TYPICAL CHARACTERISTICS (continued)**


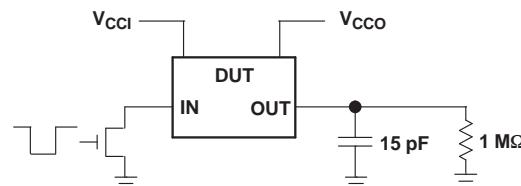
## TYPICAL CHARACTERISTICS (continued)



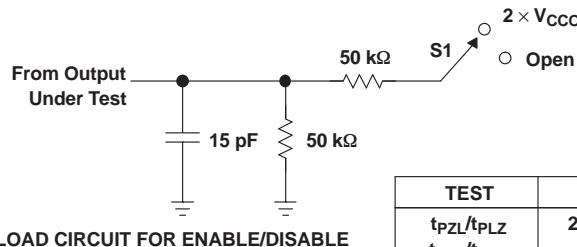
## PARAMETER MEASUREMENT INFORMATION



DATA RATE, PULSE DURATION, PROPAGATION DELAY,  
OUTPUT RISE AND FALL TIME MEASUREMENT USING  
A PUSH-PULL DRIVER



DATA RATE, PULSE DURATION, PROPAGATION DELAY,  
OUTPUT RISE AND FALL TIME MEASUREMENT USING  
AN OPEN-DRAIN DRIVER

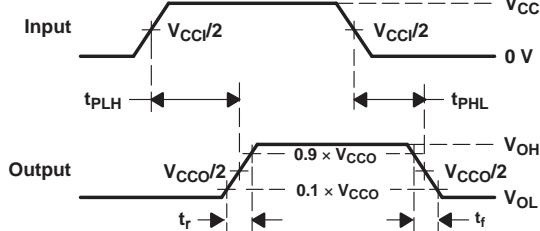


LOAD CIRCUIT FOR ENABLE/DISABLE  
TIME MEASUREMENT

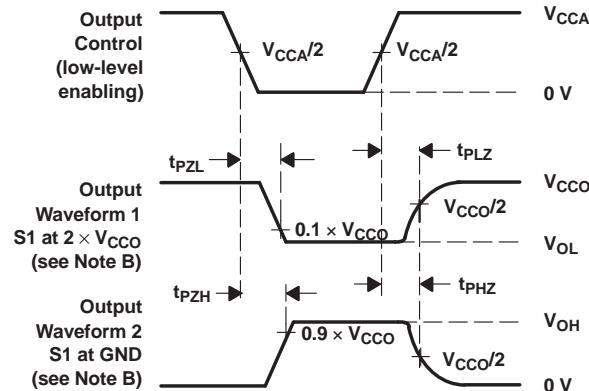
TEST	S1
$t_{PZL}/t_{PLZ}$	$2 \times V_{CCO}$
$t_{PHZ}/t_{PZH}$	Open



VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES

- A.  $C_L$  includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $dv/dt \geq 1 \text{ V/ns}$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PLZ}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H.  $V_{CCI}$  is the  $V_{CC}$  associated with the input port.
- I.  $V_{CCO}$  is the  $V_{CC}$  associated with the output port.
- J. All parameters and waveforms are not applicable to all devices.

**Figure 8. Load Circuit and Voltage Waveforms**

## PRINCIPLES OF OPERATION

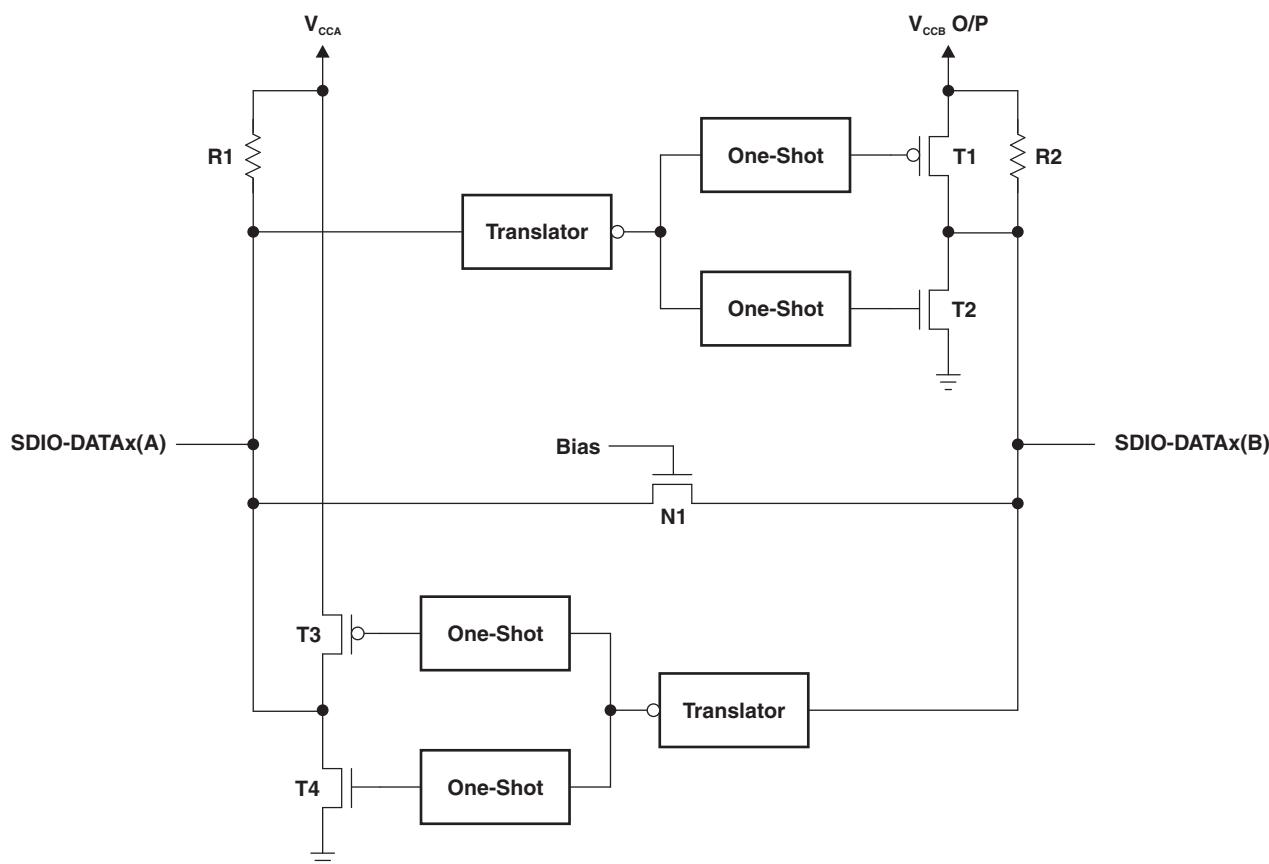
### Applications

The TXS0206-29 device is a complete application-specific voltage-translator designed to bridge the digital-switching compatibility gap and interface logic threshold levels between a microprocessor with MMC, SD, and Memory Stick™ cards. It is intended to be used in a point-to-point topology when interfacing these devices that may or may not be operating at different interface voltages.

### Architecture

The CLKA, CLKB, and CLK-f subsystem interfaces consist of a fully-buffered voltage translator design that has its output transistors to source and sink current optimized for drive strength.

The SDIO lines comprise a semi-buffered auto-direction-sensing based translator architecture (see [Figure 9](#)) that does not require a direction-control signal to control the direction of data flow of the A to B ports (or from B to A ports).



**Figure 9. Architecture of an SDIO Switch-Type Cell**

Each of these bidirectional SDIO channels independently determines the direction of data flow without a direction-control signal. Each I/O pin can be automatically reconfigured as either an input or an output, which is how this auto-direction feature is realized.

The following two key circuits are employed to facilitate the "switch-type" voltage translation function:

1. Integrated pullup resistors to provide dc-bias and drive capabilities
2. An N-channel pass-gate transistor topology (with a high  $R_{ON}$  of  $\sim 300 \Omega$ ) that ties the A-port to the B-port
3. Output one-shot (O.S.) edge-rate accelerator circuitry to detect and accelerate rising edges on the A or B ports

For bidirectional voltage translation, pullup resistors are included on the device for dc current sourcing capability. The  $V_{GATE}$  gate bias of the N-channel pass transistor is set at a level that optimizes the switch characteristics for maximum data rate as well as minimal static supply leakage. Data can flow in either direction without guidance from a control signal.

The edge-rate acceleration circuitry speeds up the output slew rate by monitoring the input edge for transitions, helping maintain the data rate through the device.

During a low-to-high signal rising-edge, the O.S. circuits turn on the PMOS transistors ( $T_1$ ,  $T_3$ ) and its associated driver output resistance of the driver is decreased to approximately  $50\ \Omega$  to  $70\ \Omega$  during this acceleration phase to increase the current drive capability of the driver for approximately 30 ns or 95% of the input edge, whichever occurs first. This edge-rate acceleration provides high ac drive by bypassing the internal pullup resistors during the low-to-high transition to speed up the rising-edge signal.

During a high-to-low signal falling-edge, the O.S. circuits turn on the NMOS transistors ( $T_2$ ,  $T_4$ ) and its associated driver output resistance of the driver is decreased to approximately  $50\ \Omega$  to  $70\ \Omega$  during this acceleration phase to increase the current drive capability of the driver for approximately 30 ns or 95% of the input edge, whichever occurs first.

To minimize dynamic  $I_{CC}$  and the possibility of signal contention, the user should wait for the O.S. circuit to turn-off before applying a signal in the opposite direction. The worst-case duration is equal to the minimum pulse-width number provided in the *Timing Requirements* section of this data sheet.

Once the O.S. is triggered and switched off, both the A and B ports must go to the same state (i.e. both High or both Low) for the one-shot to trigger again. In a DC state, the output drivers maintain a Low state through the pass transistor. The output drivers maintain a High through the "smart pullup resistors" that dynamically change value based on whether a Low or a High is being passed through the SDIO lines, as follows:

- $R_{PU1}$  and  $R_{PU2}$  values are a nominal  $40\ k\Omega$  when the output is driving a low
- $R_{PU1}$  and  $R_{PU2}$  values are a nominal  $4\ k\Omega$  when the output is driving a high
- $R_{PU1}$  and  $R_{PU2}$  values are a nominal  $70\ k\Omega$  when the device is disabled via the EN pin or by pulling the either  $V_{CCA}$  or  $V_{CCBO/P}$  to 0 V.

The reason for using these "smart" pullup resistors is to allow the TXS0206-29 to realize a lower static power consumption (when the I/Os are low), support lower  $V_{OL}$  values for the same size pass-gate transistor, and improved simultaneous switching performance.

## Input Driver Requirements

The continuous dc-current "sinking" capability is determined by the external system-level driver interfaced to the SDIO pins. Since the high bandwidth of these bidirectional SDIO circuits necessitates the need for a port to quickly change from an input to an output (and vice-versa), they have a modest dc-current "sourcing" capability of hundreds of micro-Amps, as determined by the smart pullup resistor values.

The fall time ( $t_{fA}$ ,  $t_{fB}$ ) of a signal depends on the edge rate and output impedance of the external device driving the SDIO I/Os, as well as the capacitive loading on these lines.

Similarly, the  $t_{pd}$  and max data rates also depend on the output impedance of the external driver. The values for  $t_{fA}$ ,  $t_{fB}$ ,  $t_{pd}$ , and maximum data rates in the data sheet assume that the output impedance of the external driver is less than  $50\ \Omega$ .

## Output Load Considerations

TI recommends careful PCB layout practices with short PCB trace lengths to avoid excessive capacitive loading and to ensure that proper O.S. triggering takes place. PCB signal trace-lengths should be kept short enough such that the round trip delay of any reflection is less than the one-shot duration. This improves signal integrity by ensuring that any reflection sees a low impedance at the driver. The O.S. circuits have been designed to stay on for approximately 30 ns. The maximum capacitance of the lumped load that can be driven also depends directly on the one-shot duration. With very heavy capacitive loads, the one-shot can time-out before the signal is driven fully to the positive rail. The O.S. duration has been set to best optimize trade-offs between dynamic  $I_{CC}$ , load driving capability, and maximum bit-rate considerations. Both PCB trace length and connectors add to the capacitance that the TXS0206-29 SDIO output sees, so it is recommended that this lumped-load capacitance be considered and kept below 50 pF to avoid O.S. retriggering, bus contention, output signal oscillations, or other adverse system-level affects.

When using the TXS0206-29 device with MMCs, SD, and Memory Stick™ to ensure that a valid receiver input voltage high ( $V_{IH}$ ) is achieved, the value of any pulldown resistors (external or internal to a memory card) must not be  $>10\text{-k}\Omega$  value. The impact of adding too heavy a pulldown resistor (i.e.  $<10\text{-k}\Omega$  value) to the data and command lines of the TXS0206-29 device and the resulting 4-k $\Omega$  pullup & 10-k $\Omega$  pulldown voltage divider network has a direct impact on the  $V_{IH}$  of the signal being sent into the memory card and its associated logic.

The resulting  $V_{IH}$  voltage for the 10-k $\Omega$  pulldown resistor value would be:

$$V_{CC} \times 10 \text{ k}\Omega / (10 \text{ k}\Omega + 4 \text{ k}\Omega) = 0.714 \times V_{CC}$$

This is marginally above a valid input high voltage for a 1.8-V signal (i.e.,  $0.65 \times V_{CC}$ ).

The resulting  $V_{IH}$  voltage for 20-k $\Omega$  pulldown resistor value would be:

$$V_{CC} \times 20 \text{ k}\Omega / (20 \text{ k}\Omega + 4 \text{ k}\Omega) = 0.833 \times V_{CC}$$

Which is above the valid input high voltage for a 1.8-V signal of  $0.65 \times V_{CC}$ .

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TXS0206-29YFPRB	ACTIVE	DSBGA	YFP	20	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(3V, 3V2)	<b>Samples</b>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

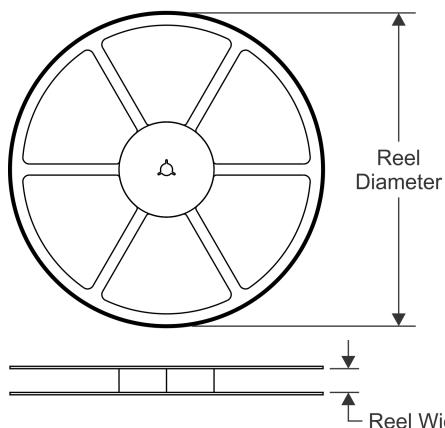
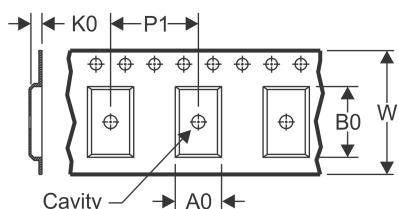
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

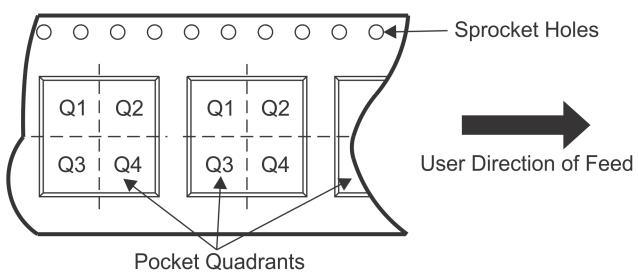
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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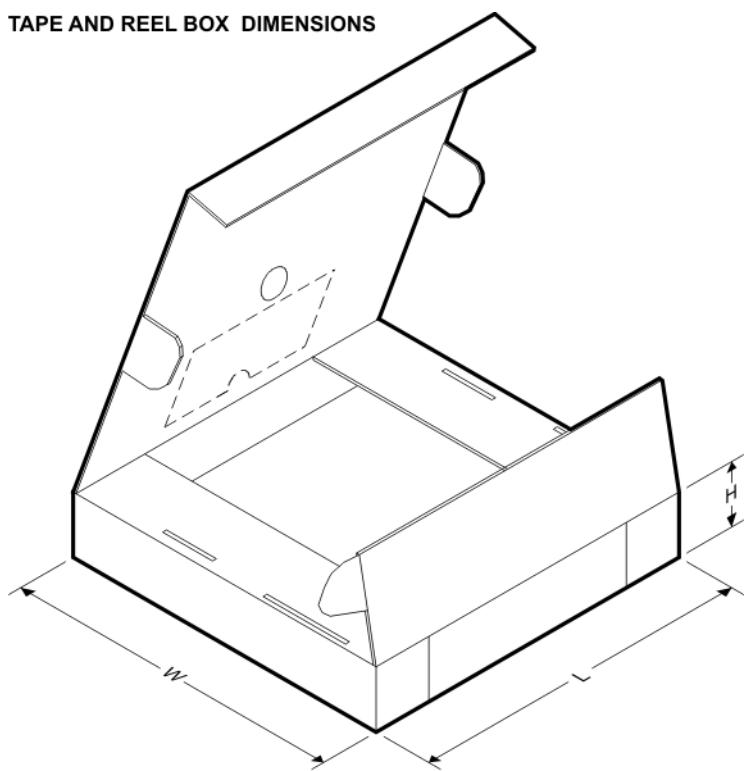
**TAPE AND REEL INFORMATION**
**REEL DIMENSIONS**

**TAPE DIMENSIONS**


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TXS0206-29YFPRB	DSBGA	YFP	20	3000	180.0	8.4	1.66	2.06	0.56	4.0	8.0	Q1

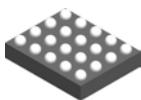
**TAPE AND REEL BOX DIMENSIONS**

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TXS0206-29YFPRB	DSBGA	YFP	20	3000	182.0	182.0	20.0

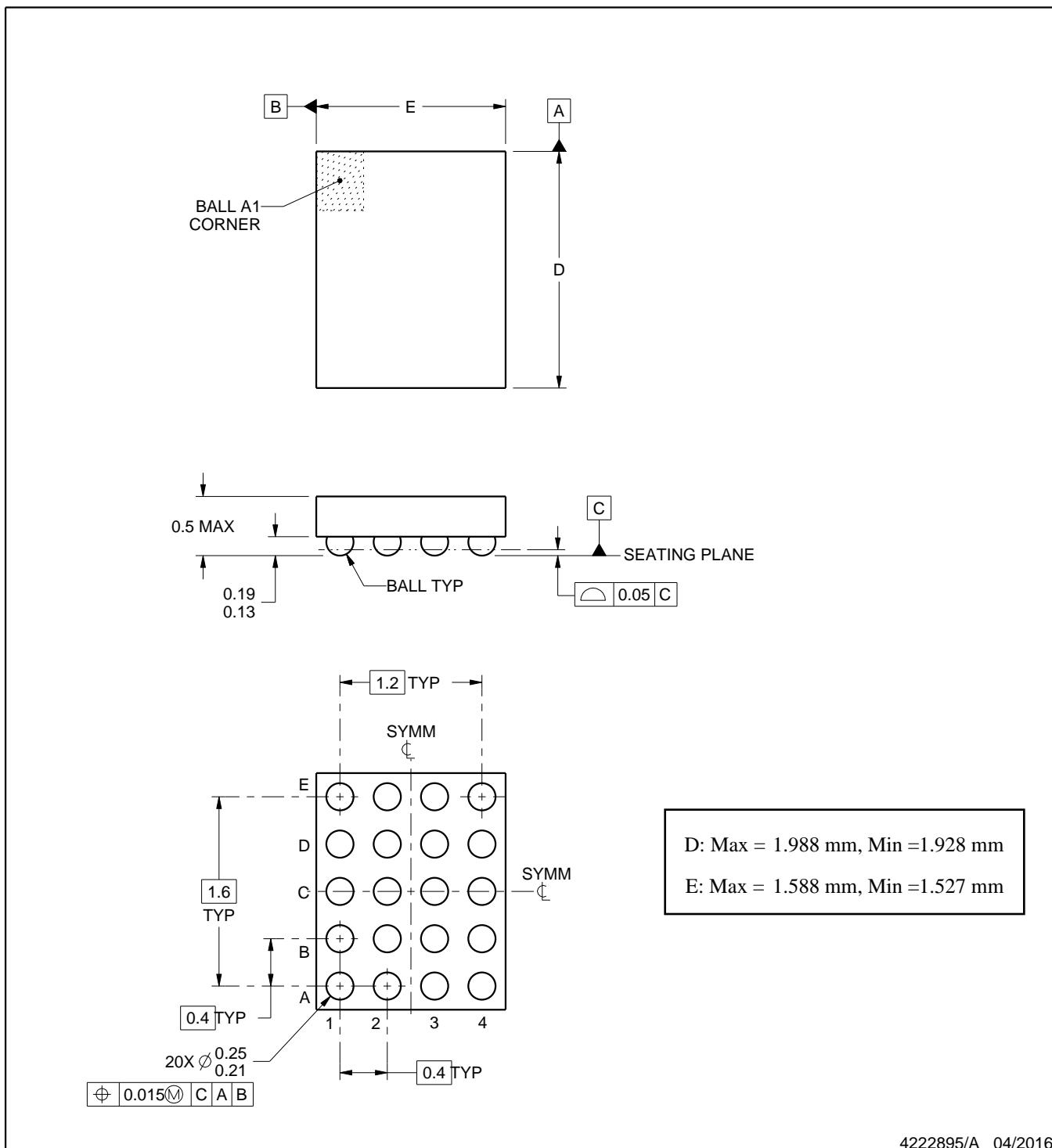
# PACKAGE OUTLINE

YFP0020



DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



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## NOTES:

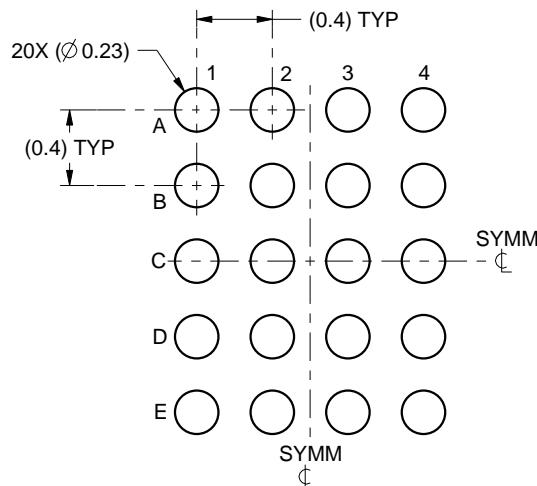
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

YFP0020

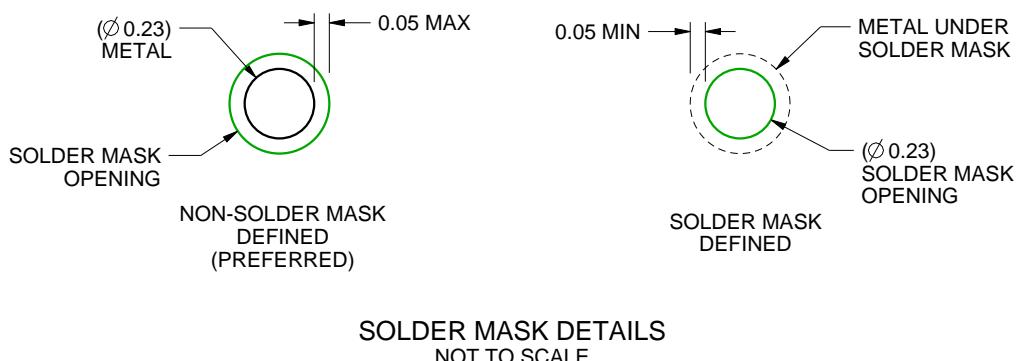
DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE

SCALE:25X



SOLDER MASK DETAILS  
NOT TO SCALE

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NOTES: (continued)

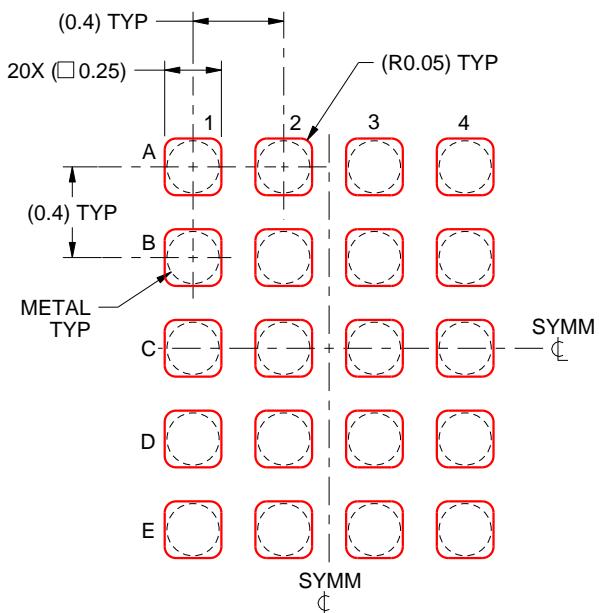
3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.  
For more information, see Texas Instruments literature number SNVA009 ([www.ti.com/lit/snva009](http://www.ti.com/lit/snva009)).

## EXAMPLE STENCIL DESIGN

YFP0020

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



**SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICK STENCIL  
SCALE:30X**

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#### NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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